

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

Bi-CMOS LSI LV5747QA — 1-channel Step-down Switching Regulator

Overview

The LV5747QA is a 1-channel step-down switching regulator.

Functions

- 1 channel step-down switching regulator controller.
- Frequency decrease function at pendent.
- · Load-independent soft start circuit.
- ON/OFF function.
- Built-in pulse-by-pulse OCP circuit. It is detected by using ON resistance of an external MOS.

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter		Symbol	Conditions	Ratings	Unit
Su	oply voltage	V _{IN} max		45	V
Allowable pin voltage	V _{IN} , SW			45	V
	HDRV, CBOOT			52	V
	LDRV			6.0	V
	Between CBOOT to SW, Between CBOOT to HDRV			6.0	V
	EN, ILIM			V _{IN} +0.3	V
	Between VIN to ILIM			1.0	V
	V _{DD}			6.0	V
	SS, FB, COMP			V _{DD} +0.3	V
Allowable Power dissipation		Pd max	Mounted on a specified board. *	0.65	W
Junction temperature		Tj max		150	°C
Operating temperature		Topr		-40 to +85	°C
Storage temperature		Tstg		-55 to +150	°C

* Specified board: 24mm × 15mm × 1.6mm, glass epoxy 2-layer board.

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LV5747QA

Recommended Operating Ranges at $Ta = 25^{\circ}C$

Parameter Symbol		Conditions	Ratings	Unit
Supply voltage range	VIN		8.0 to 42	V
Error amplifier input voltage	V _{FB}		0 to 1.6	V

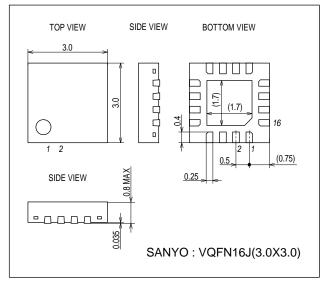
Electrical Characteristics at Ta = 25°C, $V_{IN} = 24V$

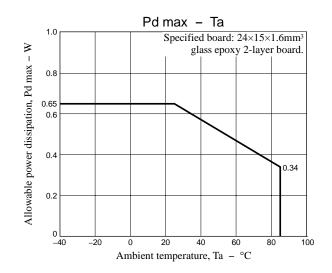
Parameter	Symbol	Conditions	Ratings			Unit
i didilicici	Cymbol		min	typ	max	011
Reference voltage block	1	1	1			
Internal reference voltage	Vref	Including offset of E/A	0.698	0.708	0.718	V
5V power supply	V _{DD}	I _{OUT} = 0 to 5mA	4.7	5.2	5.7	V
Triangular waveform oscillator blo	ck					
Oscillation frequency	Fosc		335	385	435	kHz
Frequency variation	FOSC DV	V _{IN} = 8 to 42V		1		%
Oscillation frequency fold back detection voltage	VOSC FB	FB voltage detection after SS ends		0.5		V
Oscillatory frequency after fold back	FOSC FB	V _{FB} = 0V	25	45	60	kHz
ON/OFF circuit block		•	·		•	
IC start-up voltage	V _{EN} on	V _{IN} = 8 to 42V		3.4	4.3	V
start-up voltage hysteresis	V _{EN} hys		1.0	1.2		V
Soft start circuit block		1	I			
Soft start source current	I _{SS} SC	EN > 4.3V	4	5	6	μA
Soft start sink current	I _{SS} SK	EN < 1V, V _{DD} = 5V		2		mA
Soft start end voltage	V _{SS} END		0.9	1.1	1.3	V
UVLO circuit block		1	0.0			
UVLO lock release voltage	VUVLO		7.0	7.4	7.8	V
UVLO hysteresis	VUVLO H		1.0	0.6	7.0	V
Error amplifier	VUVLO H			0.0		v
	L				100	~ ^
Input bias current	IEA IN		4000	4.400	100	nA
Error amplifier gain	G _{EA}		1000	1400	1800	μA/
Common mode input range	V _{EA R}	V _{IN} = 8 to 42V	0.0		1.6	V
Sink output current	IEA OSK	FB = 1.0V		-100		μA
Source output current	IEA OSC	FB = 0V		100		μA
Current detection amplifier gain	GISNS			1.3		
over current limiter circuit block	1	1				
Reference current	ILIM		-10%	20	+10%	μA
Over current detection comparator offset voltage	VLIM OFS		-5		+5	m∖
Over current detection comparator			V _{IN} -0.45		VIN	V
common mode input range						
PWM comparator	1.4			T		
Input threshold voltage	Vt max	Duty cycle = DMAX, SW = V _{IN}	1.0	1.1	1.2	V
	Vt0	Duty cycle = 0%, SW = V_{IN}	0.4	0.5	0.6	V
Maximum ON duty	DMAX		85	90	95	%
Output block		Τ				-
Output stage ON resistance (the upper side)	R _{ONH}			5		Ω
Output stage ON resistance (the under side)	R _{ONL}			5		Ω
Output stage ON current (the upper side)	IONH		240			mA
Output stage ON current (the under side)	IONL		240			mA
The whole device						
Standby current	ICCS	EN < 1V			60	μA
Mean consumption current	ICCA	EN > 4.3V		3.3		mA

Package Dimensions

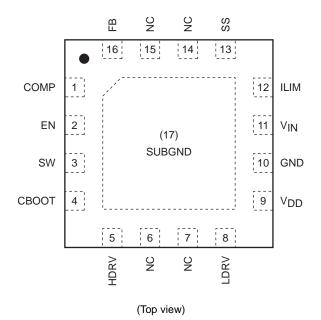
unit : mm (typ)

3444





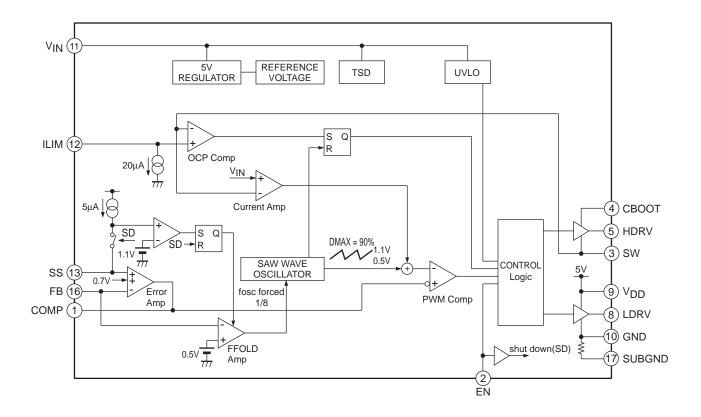
Pin Assignment



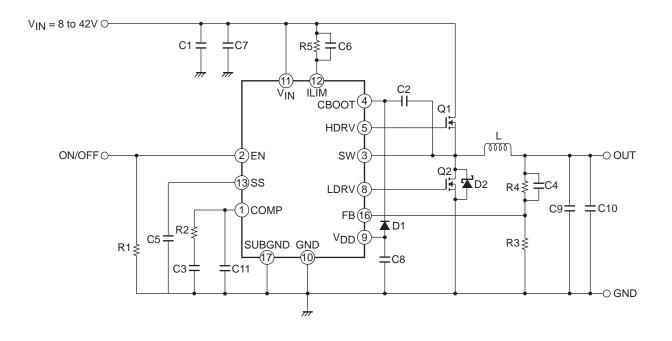
Pin Function

Pin No.	Pin name	Description
1	COMP	Error amplifier output pin. Connect a phase compensation circuit between this pin and FB.
2	EN	ON/OFF pin.
3	SW	Pin to connect with switching node. The source of NchMOSFET connects to this pin.
4	CBOOT	Bootstrap capacity connection pin. This pin becomes a GATE drive power supply of an external NchMOSFET.
		Connect a bypath capacitor between CBOOT and SW.
5	HDRV	An external the upper MOSFET gate drive pin.
6, 7,	NC	NC denotes no internal connection.
14, 15		
8	LDRV	An external the lower MOSFET gate drive pin.
9	V _{DD}	Power supply pin for an external the lower MOS-FET gate drive.
10	GND	Ground pin. Each reference voltage is based on the voltage of the ground pin.
11	V _{IN}	Power supply pin. This pin is monitored by UVLO function. When the voltage of this pin becomes 7.8V or more by UVLO function, The IC starts and the soft start function operates.
12	ILIM	Reference current pin for current detection. The sink current of about 20µA flows to this pin. When a resistance is connected between this pin and V _{IN} outside and the voltage applied to the SW pin is lower than the voltage of the terminal side of the resistance, the upper NchMOSFET is off by operating the current limiter comparator. This operation is reset with respect to each PWM pulse.
13	SS	Pin to connect a capacitor for soft start. A capacitor for soft start is charged by using the voltage of about 5µA. This pin ends the soft start period by using the voltage of about 1.1V and the frequency fold back function becomes active.
16	FB	Error amplifier reverse input pin. By operating the converter, the voltage of this pin becomes 0.708V. The voltage in which the output voltage is divided by an external resistance is applied to this pin. Moreover, when this pin voltage becomes 0.5V or less after a soft start ends, the frequency fold back function operations, and the oscillating frequency is falling with the FB voltage.
17	SUBGND	It is connected to SUB of the IC. Thus, use it with electric potential same as a GND pin.

Block Diagram



Sample Application Circuit



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